

## SD9608 OVERVIEW

The SD9608 is a dual-channel, 10-bit, analog-to-digital converter (ADC) supporting sampling rates up to 105MSps. The device uses a multistage pipeline architecture to achieve high signal-to-noise ratio (SNR) and linearity, over wide input signal bandwidth. The SD9608 can be set to operate using either CMOS or LVDS output interface. Programming for configuration and control is accomplished using a 3-wire SPI-compatible serial bus. The digital output data can be programmed to be delivered in offset binary, twos complement format, or gray code.

## FEATURES

- SNR: 61.4dBFS at  $f_{IN} = 70.2\text{MHz}$  and  $f_S = 105\text{MSps}$
- SFDR: 81.0dBc at  $f_{IN} = 70.2\text{MHz}$  and  $f_S = 105\text{MSps}$
- -139.2dBFS/Hz input-noise at  $f_{IN} = 70.2\text{MHz}$  and  $f_S = 105\text{MSps}$
- 2.0V<sub>p-p</sub> nominal input
- Typical power consumption: 255mW at 105MSps
- Integer 1-to-8 input clock divider (840MHz maximum input rate)
- Sample rates of up to 105MSps
- 1.8V analog supply voltage
- LVDS (ANSI-644 levels) outputs
- Internal ADC voltage reference
- ADC clock duty cycle correction
- Serial port control
- Energy saving power-down modes

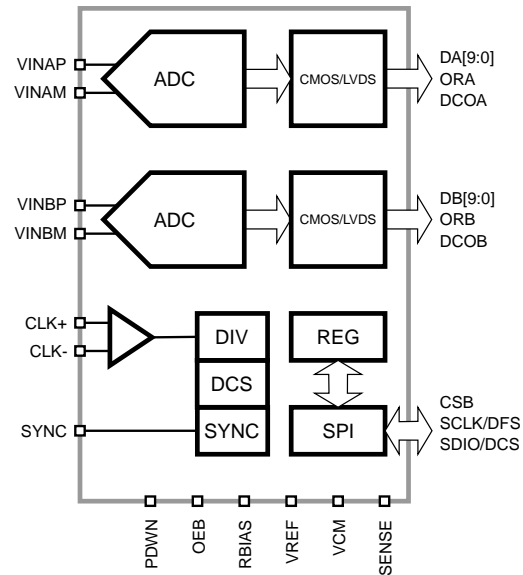


Figure 1: SD9608 Functional Block Diagram.

## APPLICATIONS

- Communications
- General-purpose software radios
- I/Q demodulation systems
- Diversity radio systems
- Smart antenna systems
- Multimode digital receivers
- Ultrasound equipment
- Broadband data applications

## Table of Contents

SPECIFICATIONS .....	1
DC Specifications .....	1
AC Specifications .....	2
Digital Specification .....	3
Switching Specifications .....	5
Output Modes .....	6
Output Timing Control .....	6
CMOS→LVDS Conversion .....	7
ABSOLUTE MAXIMUM RATINGS .....	8
PACKAGE .....	9
TYPICAL PERFORMANCE CHARACTERISTICS .....	13
EQUIVALENT CIRCUITS .....	15
THEORY OF OPERATION .....	17
ADC Architecture .....	17
Stand-by and Power-Down Modes .....	18
Pin Functions .....	18
SERIAL PORT INTERFACE .....	20
OUTPUT MODE .....	21
Data Scrambler .....	21
Alternate Bit Polarity .....	21
Output Test Modes .....	21
CONTROL REGISTERS .....	23
0x400 - CHIP_TOP .....	23
0xF00 - ADC_DUAL .....	26
0xDC0 - ADC_A .....	27
0xCC1 - ADC_B .....	29
ORDERING INFORMATION .....	32
PACKAGE DRAWING .....	33
REVISION HISTORY .....	34

## SPECIFICATIONS

### DC Specifications

At  $T_A = 25^\circ\text{C}$ ,  $V_{AVDD} = 1.8\text{V}$ ,  $V_{DRVDD} = 1.8\text{V}$ ,  $F_{CLK} = 105\text{MHz}$ ,  $A_{IN} = -1\text{dBFS}$ , differential AC-coupled external clock source, LVDS mode, unless otherwise noted.

Table 1. DC Specifications.

PARAMETER	TEMP	MIN	TYP	MAX	UNIT
Resolution			10		bits
Accuracy					
No Missing Codes	Full		Guaranteed		
Offset Error	Full	-1.00		1.00	%FSR
Gain Error	Full	-3.50		1.50	%FSR
DNL	Full			$\pm 0.3$	LSB
INL	Full			$\pm 0.4$	LSB
Matching					
Offset Error	25°C	-1.20		1.20	%FSR
Gain Error	25°C	-0.40		0.40	%FSR
Temperature Drift					
Offset Error	Full		$\pm 0.5$		ppm/°C
Gain Error	Full		80.0		ppm/°C
Internal Voltage Reference					
Output Voltage	Full	1.01		1.06	V
External Voltage Reference					
Range	Full	0.90		1.07	V
Input Referred Noise					
$V_{REF} = 1.0\text{V}$	25°C		0.29		LSB(rms)
Analog Input					
Input Span, $V_{REF} = 1.04\text{V}$	Full		2.0		V
Input Capacitance	Full		3.0		pF
Input Resistance	Full		2.0		k $\Omega$
Input Common-Mode Voltage	Full		0.70		V
Input Common-Mode Range	Full	0.62		0.80	V
VCM Voltage	Full		0.68		V
VCM Current Capability	Full		100		$\mu\text{A}$
Reference Input Resistance	Full		50		k $\Omega$
Power Supply					
$V_{AVDD}$	Full	1.7	1.8	1.9	V
$V_{DRVDD}$	Full	1.7	1.8	1.9	$\mu\text{A}$
$I_{AVDD} @ 1.8\text{V}$	Full		125.0	155.0	mA
$I_{DRVDD} @ 1.8\text{V (CMOS)}$	Full		16.6	20.8	mA
$I_{DRVDD} @ 1.8\text{V (LVDS)}$	Full		44.0	58.0	mA
Power Consumption					
Sine Wave Input	Full		255.0		mW
Standby <sup>1</sup>	Full		60.0		mW
Power Down	Full		8.0		mW

<sup>1</sup> Standby power is measured with a sinewave input and active clock.

## AC Specifications

At  $T_A = 25^\circ\text{C}$ ,  $V_{AVDD} = 1.8\text{V}$ ,  $V_{DRVDD} = 1.8\text{V}$ ,  $F_{CLK} = 105\text{MHz}$ ,  $A_{IN} = -1\text{dBFS}$ , differential AC-coupled external clock source, High-Performance Calibration Mode enabled, LVDS mode, unless otherwise noted.

Table 2. AC Specifications.

PARAMETER	TEMP	MIN	TYP	MAX	UNIT
Signal-to-Noise Ratio (SNR)					
$f_{IN} = 6.55\text{MHz}$	$25^\circ\text{C}$		61.4		dBFS
$f_{IN} = 70.2\text{MHz}$	$25^\circ\text{C}$		61.4		dBFS
	Full	61.0			dBFS
$f_{IN} = 140\text{MHz}$	$25^\circ\text{C}$		61.2		dBFS
$f_{IN} = 220\text{MHz}$	$25^\circ\text{C}$		60.9		dBFS
Signal-to-Noise and Distortion Ratio (SNDR)					
$f_{IN} = 6.55\text{MHz}$	$25^\circ\text{C}$		61.3		dBFS
$f_{IN} = 70.2\text{MHz}$	$25^\circ\text{C}$		61.3		dBFS
	Full	60.6			dBFS
$f_{IN} = 140\text{MHz}$	$25^\circ\text{C}$		61.1		dBFS
$f_{IN} = 220\text{MHz}$	$25^\circ\text{C}$		60.6		dBFS
Effective Number of Bits (ENOB)					
$f_{IN} = 6.55\text{MHz}$	$25^\circ\text{C}$		9.9		bits
$f_{IN} = 70.2\text{MHz}$	$25^\circ\text{C}$		9.9		bits
$f_{IN} = 140\text{MHz}$	$25^\circ\text{C}$		9.9		bits
$f_{IN} = 220\text{MHz}$	$25^\circ\text{C}$		9.8		bits
Worst 2 <sup>nd</sup> or 3 <sup>rd</sup> Harmonic Power					
$f_{IN} = 6.55\text{MHz}$	$25^\circ\text{C}$		-82.0		dBc
$f_{IN} = 70.2\text{MHz}$	$25^\circ\text{C}$		-82.0	-78.0	dBc
$f_{IN} = 140\text{MHz}$	$25^\circ\text{C}$		-79.0		dBc
$f_{IN} = 220\text{MHz}$	$25^\circ\text{C}$		-74.0		dBc
Worst non-Harmonic Power					
$f_{IN} = 6.55\text{MHz}$	$25^\circ\text{C}$		-82.0		dBc
$f_{IN} = 70.2\text{MHz}$	$25^\circ\text{C}$		-81.0	-76.0	dBc
$f_{IN} = 140\text{MHz}$	$25^\circ\text{C}$		-81.0		dBc
$f_{IN} = 220\text{MHz}$	$25^\circ\text{C}$		-79.0		dBc
Spurious-Free Dynamic Range <sup>1</sup> (SFDR)					
$f_{IN} = 6.55\text{MHz}$	$25^\circ\text{C}$		82.0		dBc
$f_{IN} = 70.2\text{MHz}$	$25^\circ\text{C}$		81.0		dBc
	Full	73.0			dBc
$f_{IN} = 140\text{MHz}$	$25^\circ\text{C}$		79.0		dBc
$f_{IN} = 220\text{MHz}$	$25^\circ\text{C}$		74.0		dBc
Two-Tone SFDR					
$f_{IN1} = 29.1\text{MHz}$ , $f_{IN2} = 30.6\text{MHz}$	$25^\circ\text{C}$		80.7		dBc
Crosstalk <sup>2</sup>	$25^\circ\text{C}$		-105.0		dBc
Analog Input Bandwidth	Full		650.0		MHz

<sup>1</sup> SFDR excludes the DC and  $f_s/2$  bins.

<sup>2</sup> Crosstalk is measured at 100MHz with -1.0dBFS on one channel and no input on the alternate channel.

## Digital Specification

$V_{AVDD} = 1.8V$ ,  $V_{DRVDD} = 1.8V$ ,  $F_{CLK} = 105MHz$ ,  $A_{IN} = -1dBFS$ , differential AC-coupled external clock source, DCS disabled, unless otherwise noted.

Table 3. Differential Clock Input.

PARAMETER	TEMP	MIN	TYP	MAX	UNIT
Logic Compliance	Full	CMOS/LVDS/LVPECL			
Internal Common-Mode Bias	Full		0.9		V
Differential Input Voltage	Full	0.3		1.2	V <sub>p-p</sub>
Input Voltage Range	Full	$V_{AGND}-0.3$		$V_{AVDD}+0.2$	V
Input Common-Mode Range	Full	0.75		1.05	V
High Level Input Current	Full	-10		10	μA
Low Level Input Current	Full	-10		10	μA
Input Capacitance	Full		1.7		pF
Input Resistance	Full		6.0		kΩ

Table 4. SYNC Input.

PARAMETER	TEMP	MIN	TYP	MAX	UNIT
Logic Compliance	Full	CMOS			
Input Voltage Range	Full	$V_{AGND}$		$V_{AVDD}$	V
High Level Input Voltage	Full	1.22		$V_{AVDD}$	V
Low Level Input Voltage	Full	$V_{AGND}$		0.50	V
High Level Input Current	Full	-1		1	μA
Low Level Input Current	Full	-1		1	μA
Input Capacitance	Full		1.5		pF
Input Resistance	Full		100		kΩ

Table 5. CSB Input.

PARAMETER	TEMP	MIN	TYP	MAX	UNIT
High Level Input Voltage	Full	1.22			V
Low Level Input Voltage	Full			0.6	V
High Level Input Current	Full	-1		1	μA
Low Level Input Current	Full	-1		1	μA
Input Capacitance	Full		1.5		pF
Input Resistance	Full		100		kΩ

Table 6. SCLK/DFS Input.

PARAMETER	TEMP	MIN	TYP	MAX	UNIT
High Level Input Voltage	Full	1.22			V
Low Level Input Voltage	Full			0.6	V
High Level Input Current	Full	-1		1	μA
Low Level Input Current	Full	-1		1	μA
Input Capacitance	Full		1.5		pF
Input Resistance	Full		100		kΩ

Table 7. SDIO/DCS Input.

PARAMETER	TEMP	MIN	TYP	MAX	UNIT
High Level Input Voltage	Full	1.22			V
Low Level Input Voltage	Full			0.6	V
High Level Input Current	Full	-1		1	$\mu$ A
Low Level Input Current	Full	-1		1	$\mu$ A
Input Capacitance	Full		1.5		pF
Input Resistance	Full		100		k $\Omega$

Table 8. OEB Input.

PARAMETER	TEMP	MIN	TYP	MAX	UNIT
High Level Input Voltage	Full	1.22			V
Low Level Input Voltage	Full			0.6	V
High Level Input Current	Full	-1		1	$\mu$ A
Low Level Input Current	Full	-1		1	$\mu$ A
Input Capacitance	Full		1.5		pF
Input Resistance	Full		100		k $\Omega$

Table 9. PDWN Input.

PARAMETER	TEMP	MIN	TYP	MAX	UNIT
High Level Input Voltage	Full	1.22			V
Low Level Input Voltage	Full			0.6	V
Pull-down Current @1.8V	Full			90	$\mu$ A
Input Capacitance	Full		1.5		pF
Input Resistance	Full		28		k $\Omega$

Table 10. CMOS Outputs (DATA and OR).

PARAMETER	TEMP	MIN	TYP	MAX	UNIT
High Level Output Voltage @50 $\mu$ A	Full	1.77			V
High Level Output Voltage @0.5mA	Full	1.75			V
Low Level Output Voltage @50 $\mu$ A	Full			0.05	V
Low Level Output Voltage @1.6mA	Full			0.10	V

Table 11. LVDS Outputs (DATA and OR).

PARAMETER	TEMP	MIN	TYP	MAX	UNIT
Differential Output Voltage ( $V_{OD}$ ), ANSI Mode	Full	250	300	450	mV
Output Offset Voltage ( $V_{OS}$ ), ANSI Mode	Full	1.10	1.13	1.30	V
Differential Output Voltage ( $V_{OD}$ ), Reduced Swing	Full	150	220	285	mV
Output Offset Voltage ( $V_{OS}$ ), Reduced Swing	Full	1.10	1.22	1.30	V

## Switching Specifications

$V_{AVDD} = 1.8V$ ,  $V_{DRVDD} = 1.8V$ ,  $F_{CLK} = 105MHz$ ,  $A_{IN} = -1dBFS$ , differential AC-coupled sine wave external clock source, DCS enabled, unless otherwise noted.

Table 12. Clock Input Timing.

PARAMETER	TEMP	MIN	TYP	MAX	UNIT
Input Clock Rate	Full			840.0	MHz
Conversion Rate (after clock divider)	Full	10.0		105.0	MHz
<i>CLK Pulse Width High (<math>t_{CH}</math>)</i>					
Divide-by-1 Mode, DCS Enabled	Full	1.5			ns
Divide-by-1 Mode, DCS Disabled	Full	4.2	4.8	5.2	ns
Divide-by-2 Mode Through Divide-by-8 Mode	Full	0.6			ns
Aperture Delay ( $t_A$ )	Full		0.5		ns
Aperture Uncertainty (Jitter, $t_J$ )	Full		140.0		fs

Table 13. SYNC Timing Requirements.

PARAMETER	MIN	TYP	MAX	UNIT
Set-Up Time ( $t_{S,SYNC}$ )		0.35		ns
Hold Time ( $t_{H,SYNC}$ )		0.35		ns

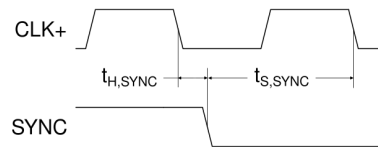


Figure 2: SYNC Input Timing.

Table 14. Data Output.

PARAMETER	TEMP	MIN	TYP	MAX	UNIT
<i>CMOS Mode</i>					
Data Propagation Delay ( $t_{PD}$ )	Full		6.0		ns
DCO Propagation Delay ( $t_{DCO}$ )	Full		7.0		ns
DCO to Data Skew ( $t_{SKEW}$ )	Full	-2.1	-1.1	-0.1	ns
Pipeline Delay (Latency, L)	Full		35.0		Cycles
<i>LVDS Mode</i>					
Data Propagation Delay ( $t_{PD}$ )	Full		8.0		ns
DCO Propagation Delay ( $t_{DCO}$ )	Full		7.7		ns
DCO to Data Skew ( $t_{SKEW}$ )	Full	-0.5	0.1	0.7	ns
Pipeline Delay (Latency, L) Channel A/Channel B	Full		32/32.5		Cycles
Wake-Up Time (from sleep)	Full		5.0		$\mu s$
Wake-Up Time (from power down)	Full		400.0		$\mu s$
Out-of-Range Recovery Time	Full		3		Cycles

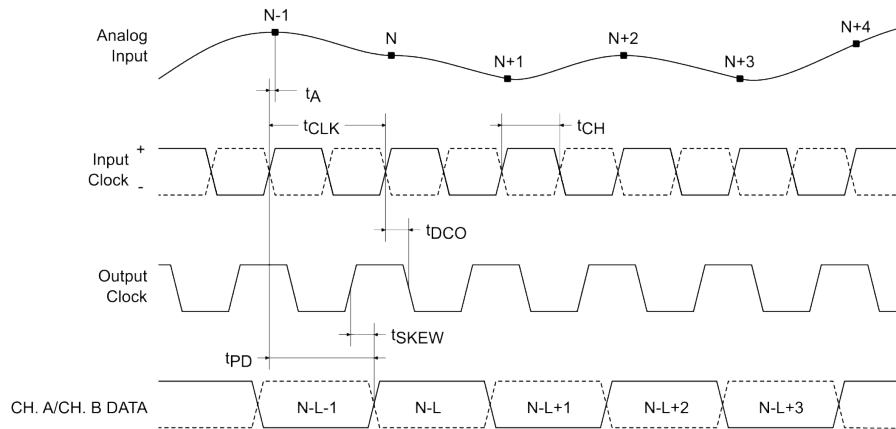


Figure 3: Parallel CMOS Output Mode Timing.

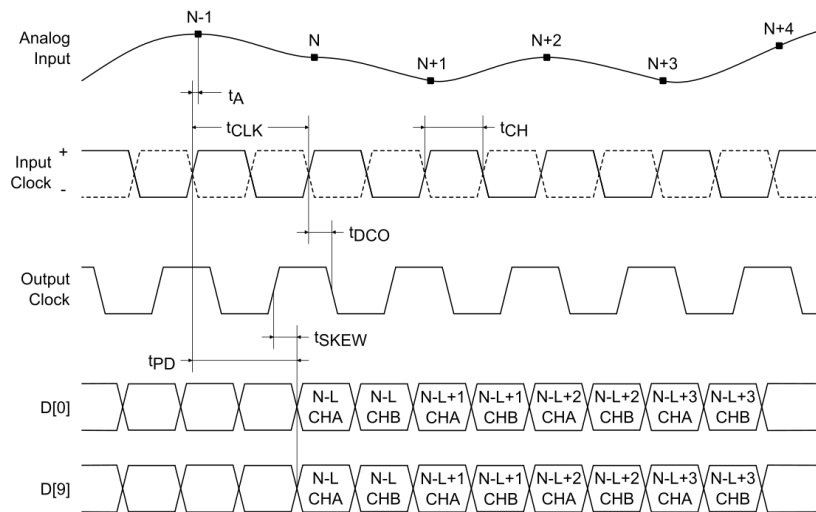


Figure 4: Parallel LVDS Output Mode Timing.

## Output Modes

The SD9608 supports both CMOS and LVDS interfaces. Two LVDS samples are sent out every clock cycle using both the rising and the falling edge of the output clock. In interleaved parallel mode, the two ADCs share the full set of output pins. The first half-cycle contains ADC A data and the second ADC B data. In multiplexed mode, each ADC has its dedicated set of output pins and the data is sent out even numbered bits on the first half-cycle and the odd bits on the second. Register *0x465*, bits [2:0], control the interleaving/multiplexing.

## Output Timing Control

Data delay control, bits [8:5], in register *0x473*, can be used to move the CMOS data relative to output clock. Bit [9] inverts the internal clock sending the data out. Bits [13:10], in register *0x473*, control the output clock delay relative to output data, while bit [14] inverts the clock. The delay step size is about 250ps.

Data delay control is not available in interleaved or multiplexed output mode.

Driving long traces or large load capacitance with CMOS output produces voltage ripple in the digital IO supply and ground, which may couple on chip to the sensitive analog circuits in the ADC and degrade the performance. This effect can be

reduced by using an external buffer IC. The use of LVDS output interface largely eliminates issues with IO supply noise.

### CMOS→LVDS Conversion

The output interface can be converted to LVDS using the register writes in Table 15, where each IO pad is programmed to a LVDS driver.

Table 15. Output Mode Conversion (CMOS→LVDS).

Register	Value	Register	Value	Register	Value	Register	Value
0x401	0xc3	0x403	0xe1	0x405	0xe1	0x407	0xe1
0x409	0xe1	0x40b	0xe1	0x40d	0xe1	0x40f	0xe1
0x411	0xe1	0x413	0xe1	0x415	0xcec1	0x417	0xe1
0x419	0xcac1	0x41b	0xe1	0x41d	0xcec1	0x41f	0xe1
0x421	0xcec1	0x423	0xe1	0x425	0xcac1	0x427	0xe1
0x429	0xc6c1	0x42b	0xe1	0x42d	0xcec1	0x42f	0xe1
0x431	0xc6c1	0x433	0xe1	0x435	0xd2c1	0x437	0xe1
0x439	0xcac1	0x43b	0xe1	0x43d	0xd2c1	0x43f	0xe1
0x441	0xcac1	0x443	0xe1	0x445	0xcac1	0x447	0xe1
0x449	0xcec1	0x44b	0xe1	0x44d	0xc3	0x44f	0xc3
0x451	0xc3	0x453	0xc3	0x466 bit[0]	0x1	0x466 bit[2]	0x0

## ABSOLUTE MAXIMUM RATINGS

Table 16. Absolute Maximum Ratings ( $T_A = 25^\circ\text{C}$ , unless otherwise specified).

Parameter	Symbol	Conditions	Min	Max	Units
AVDD	$V_{AVDD}$	Relative to AGND	-0.3	2.0	V
DRVDD	$V_{DRVDD}$	Relative to AGND	-0.3	2.0	V
VINAP/VINBP, VINAM/VINBM		Relative to AGND	-0.3	2.0	V
CLK+, CLK-		Relative to AGND	-0.3	2.0	V
SYNC		Relative to AGND	-0.3	2.0	V
RBIAS		Relative to AGND	-0.3	2.0	V
SENSE		Relative to AGND	-0.3	2.0	V
VCM		Relative to AGND	-0.3	2.0	V
VREF		Relative to AGND	-0.3	2.0	V
CSB		Relative to AGND	-0.3	2.0	V
SCLK/DFS		Relative to AGND	-0.3	2.0	V
SDIO/DCS		Relative to AGND	-0.3	2.0	V
OEB		Relative to AGND	-0.3	2.0	V
PDWN		Relative to AGND	-0.3	2.0	V
DA0, ..., DA9 DB0, ..., DB9		Relative to AGND	-0.3	2.0	V
DCO+, DCO-		Relative to AGND	-0.3	2.0	V
Operating Temperature Range (Ambient)			-40	85	°C
Maximum Junction Temperature Under Bias				125	
Storage Temperature Range (Ambient)			-65	150	

### Notes:

- Stresses beyond those listed under Table 16 may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute–maximum–rated conditions for extended periods may affect device reliability.

### ESD CAUTION.



**Electrostatic Discharge Sensitive Device.**

Proper ESD precautions should be observed to prevent performance degradation or loss of functionality.

**PACKAGE**

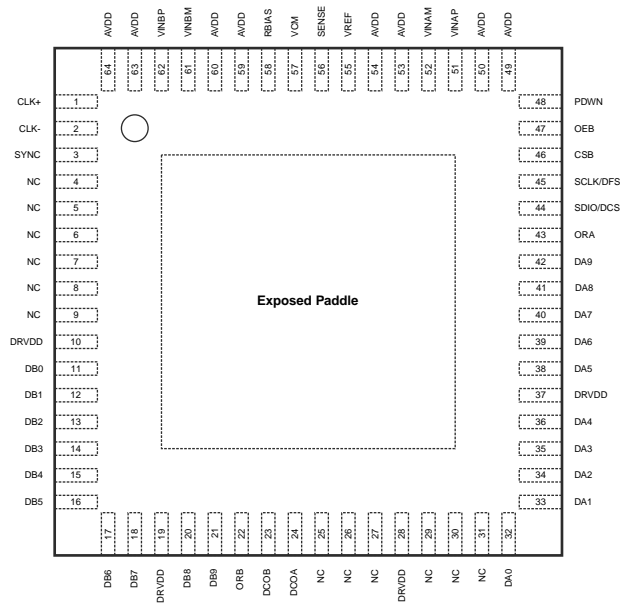


Figure 5: SD9608 Package Top View for Parallel CMOS Configuration.

1. NC = No Connect.
2. The exposed thermal pad on the bottom of the package provides the analog ground for the part and must be connected for proper operation.

Table 17. Pin Descriptions for Parallel CMOS Configuration.

Number	Name	Type	Comment
0	AGND	Ground	Exposed Paddle, Analog Ground.
1	CLK+	Input	ADC Clock Input (Plus).
2	CLK-	Input	ADC Clock Input (Minus).
3	SYNC	Input	Digital Synchronization Pin.
4, 5, 6, 7, 8, 9, 25, 26, 27, 29, 30, 31	NC		Do not connect.
10, 19, 28, 37	DRVDD	Power	Digital I/O Supply.
11	DB0	Output	Channel B CMOS Output Data 0 (LSB).
12	DB1	Output	Channel B CMOS Output Data 1.
13	DB2	Output	Channel B CMOS Output Data 2.
14	DB3	Output	Channel B CMOS Output Data 3.
15	DB4	Output	Channel B CMOS Output Data 4.
16	DB5	Output	Channel B CMOS Output Data 5.
17	DB6	Output	Channel B CMOS Output Data 6.
18	DB7	Output	Channel B CMOS Output Data 7.
20	DB8	Output	Channel B CMOS Output Data 8.
21	DB9	Output	Channel B CMOS Output Data 9.
22	ORB	Output	Channel B Overrange Output.
23	DCOB	Output	Channel B Data Clock Output.

Number	Name	Type	Comment
24	DCOA	Output	Channel A Data Clock Output.
32	DA0	Output	Channel A CMOS Output Data 0 (LSB).
33	DA1	Output	Channel A CMOS Output Data 1.
34	DA2	Output	Channel A CMOS Output Data 2.
35	DA3	Output	Channel A CMOS Output Data 3.
36	DA4	Output	Channel A CMOS Output Data 4.
38	DA5	Output	Channel A CMOS Output Data 5.
39	DA6	Output	Channel A CMOS Output Data 6.
40	DA7	Output	Channel A CMOS Output Data 7.
41	DA8	Output	Channel A CMOS Output Data 8.
42	DA9	Output	Channel A CMOS Output Data 9.
43	ORA	Output	Channel A Overrange Output.
44	SDIO/DCS	InOut	SPI Serial Data I/O/Duty Cycle Stabilizer Pin in External Pin Mode.
45	SCLK/DFS	Input	SPI Serial Clock/Data Format Select Pin in External Pin Mode.
46	CSB	Input	SPI Chip Select (Active Low).
47	OEB	Input	Output Enable Input (Active low).
48	PDWN	Input	Power-Down Input (Active High). The operation of this pin depends on the SPI mode and can be configured as power-down or standby.
49, 50, 53, 54, 59, 60, 63, 64	AVDD	Power	Analog Power Supply (1.8 V Nominal).
51	VINAP	Input	Differential Analog Input Pin (Plus) for Channel A.
52	VINAM	Input	Differential Analog Input Pin (Minus) for Channel A.
55	VREF	InOut	Voltage Reference Input/Output.
56	SENSE	Input	Reference Programming Pin.
57	VCM	Output	This pin outputs the common-mode voltage that can be used externally to bias the analog input pins.
58	RBIAS	InOut	External Reference Bias Resistor. Connect to 30 k $\Omega$ (1% tolerance) resistor to ground.
61	VINBM	Input	Differential Analog Input Pin (Minus) for Channel B.
62	VINBP	Input	Differential Analog Input Pin (Plus) for Channel B.

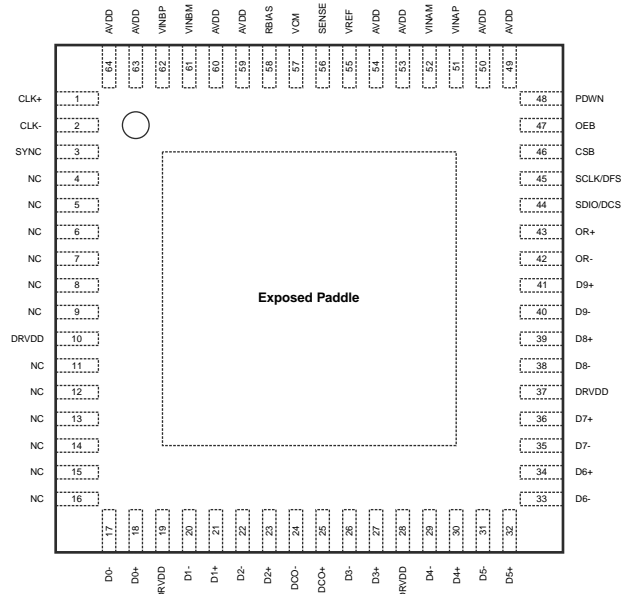


Figure 6: SD9608 Package Top View for Parallel LVDS Configuration.

1. NC = No Connect.
2. The exposed thermal pad on the bottom of the package provides the analog ground for the part and must be connected for proper operation.

Table 18. Pin Descriptions for Parallel LVDS Configuration.

Number	Name	Type	Comment
0	AGND	Ground	Exposed Paddle, Analog Ground.
1	CLK+	Input	ADC Clock Input (Plus).
2	CLK-	Input	ADC Clock Input (Minus).
3	SYNC	Input	Digital Synchronization Pin.
4, 5, 6, 7, 8, 9, 11, 12, 13, 14, 15, 16	NC		Do not connect.
10, 19, 28, 37	DRVDD	Power	Digital I/O Supply.
17	D0-	Output	Channel A/Channel B LVDS Output Data 0 (Minus).
18	D0+	Output	Channel A/Channel B LVDS Output Data 0 (Plus).
20	D1-	Output	Channel A/Channel B LVDS Output Data 1 (Minus).
21	D1+	Output	Channel A/Channel B LVDS Output Data 1 (Plus).
22	D2-	Output	Channel A/Channel B LVDS Output Data 2 (Minus).
23	D2+	Output	Channel A/Channel B LVDS Output Data 2 (Plus).
24	DCO-	Output	LVDS Data Clock Output (Minus).
25	DCO+	Output	LVDS Data Clock Output (Plus).
26	D3-	Output	Channel A/Channel B LVDS Output Data 3 (Minus).
27	D3+	Output	Channel A/Channel B LVDS Output Data 3 (Plus).
29	D4-	Output	Channel A/Channel B LVDS Output Data 4 (Minus).
30	D4+	Output	Channel A/Channel B LVDS Output Data 4 (Plus).
31	D5-	Output	Channel A/Channel B LVDS Output Data 5 (Minus).
32	D5+	Output	Channel A/Channel B LVDS Output Data 5 (Plus).

Number	Name	Type	Comment
33	D6-	Output	Channel A/Channel B LVDS Output Data 6 (Minus).
34	D6+	Output	Channel A/Channel B LVDS Output Data 6 (Plus).
35	D7-	Output	Channel A/Channel B LVDS Output Data 7 (Minus).
36	D7+	Output	Channel A/Channel B LVDS Output Data 7 (Plus).
38	D8-	Output	Channel A/Channel B LVDS Output Data 8 (Minus).
39	D8+	Output	Channel A/Channel B LVDS Output Data 8 (Plus).
40	D9-	Output	Channel A/Channel B LVDS Output Data 9 (Minus).
41	D9+	Output	Channel A/Channel B LVDS Output Data 9 (Plus).
42	OR-	Output	Channel A/Channel B LVDS Overrange (Minus).
43	OR+	Output	Channel A/Channel B LVDS Overrange (Plus).
44	SDIO/DCS	InOut	SPI Serial Data I/O/Duty Cycle Stabilizer Pin in External Pin Mode.
45	SCLK/DFS	Input	SPI Serial Clock/Data Format Select Pin in External Pin Mode.
46	CSB	Input	SPI Chip Select (Active Low).
47	OEB	Input	Output Enable Input (Active low).
48	PDWN	Input	Power-Down Input (Active High). The operation of this pin depends on the SPI mode and can be configured as power-down or standby.
49, 50, 53, 54, 59, 60, 63, 64	AVDD	Power	Analog Power Supply (1.8 V Nominal).
51	VINAP	Input	Differential Analog Input Pin (Plus) for Channel A.
52	VINAM	Input	Differential Analog Input Pin (Minus) for Channel A.
55	VREF	InOut	Voltage Reference Input/Output.
56	SENSE	Input	Reference Programming Pin.
57	VCM	Output	This pin outputs the common-mode voltage that can be used externally to bias the analog input pins.
58	RBIAS	InOut	External Reference Bias Resistor. Connect to 30 k $\Omega$ (1% tolerance) resistor to ground.
61	VINBM	Input	Differential Analog Input Pin (Minus) for Channel B.
62	VINBP	Input	Differential Analog Input Pin (Plus) for Channel B.

## TYPICAL PERFORMANCE CHARACTERISTICS

At  $T_A = 25^\circ\text{C}$ ,  $V_{AVDD} = 1.8\text{V}$ ,  $V_{DRVDD} = 1.8\text{V}$ ,  $F_{CLK} = 105\text{MHz}$ ,  $A_{IN} = -1\text{dBFS}$ , differential AC-coupled clock source, High-Performance Calibration Mode enabled, LVDS mode, unless otherwise noted.

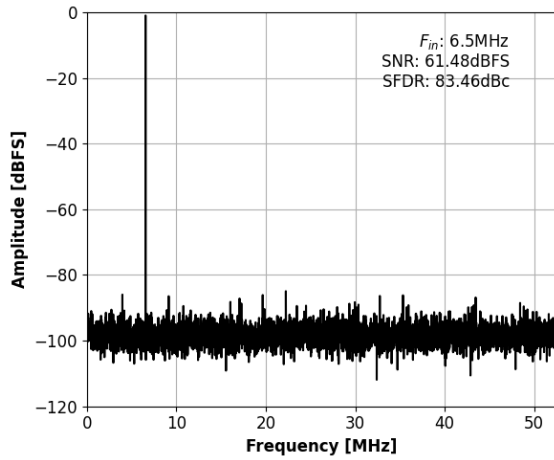


Figure 7: Single-Tone FFT with  $f_{IN}=6.55\text{MHz}$ .

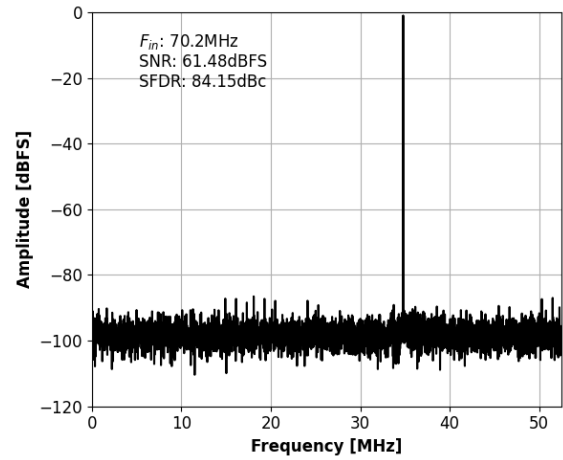


Figure 8: Single-Tone FFT with  $f_{IN}=70.2\text{MHz}$ .

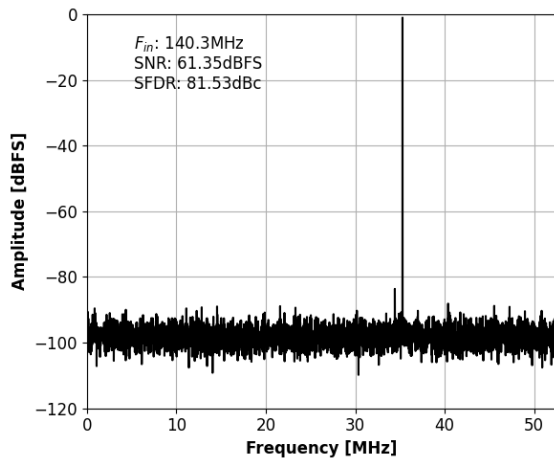


Figure 9: Single-Tone FFT with  $f_{IN}=140\text{MHz}$ .

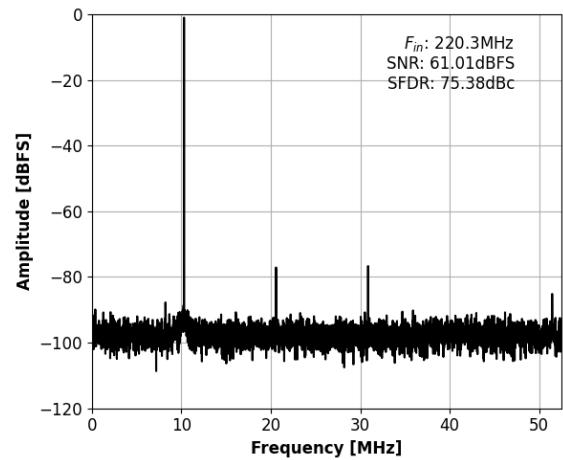


Figure 10: Single-Tone FFT with  $f_{IN}=220\text{MHz}$ .

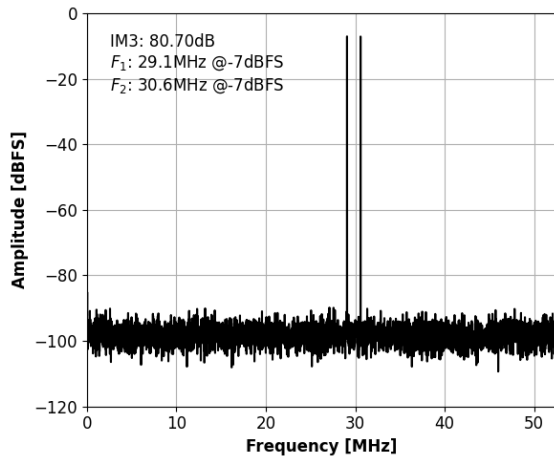


Figure 11: Two-Tone FFT with  $f_{IN1}=29.1\text{MHz}$ ,  $f_{IN2}=30.6\text{MHz}$ .

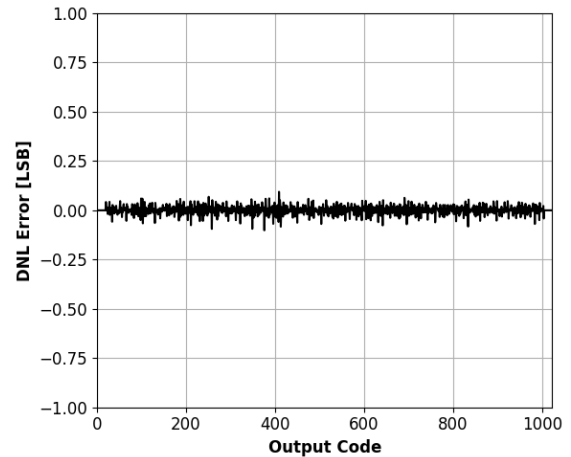


Figure 12: DNL Error with  $f_{IN}=6.55\text{MHz}$ .

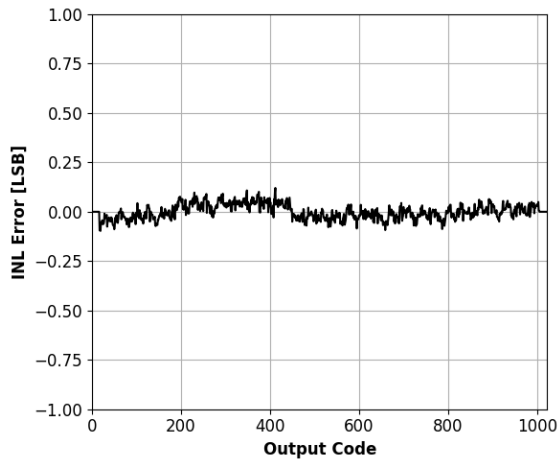


Figure 13: INL Error with  $f_{IN}=6.55\text{MHz}$ .

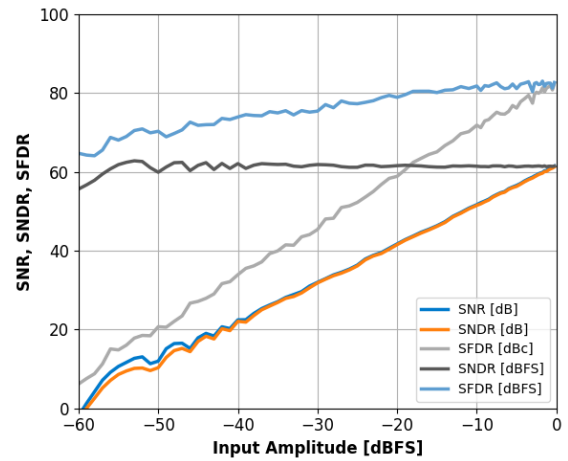


Figure 14: Single-Tone SNR, SNDR and SFDR vs. Input Amplitude with  $f_{IN}=30.25\text{MHz}$ .

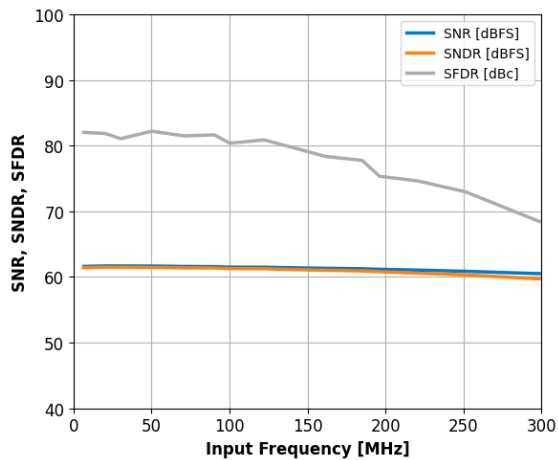


Figure 15: Single-Tone SNR, SNDR and SFDR vs. Input Frequency with  $f_s=105\text{MHz}$ .

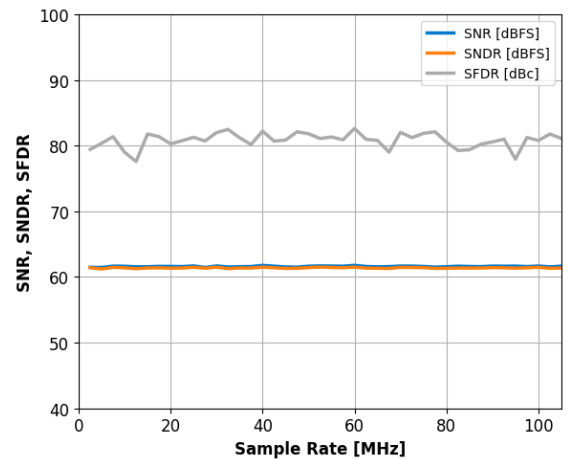


Figure 16: Single-Tone SNR, SNDR and SFDR vs. Sample Rate with  $f_{IN}=30.25\text{MHz}$ .

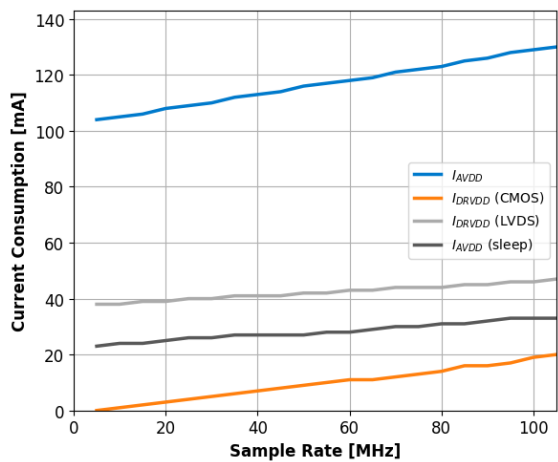


Figure 17: Current vs. Sample Rate.

**EQUIVALENT CIRCUITS**



Figure 18: Equivalent Clock Input Circuit.

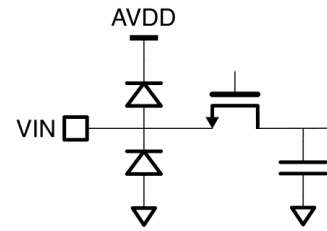


Figure 19: Equivalent Analog Input Circuit.

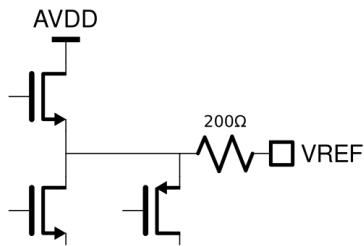


Figure 20: Equivalent VREF Circuit.

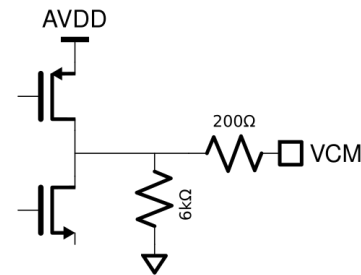


Figure 21: Equivalent VCM Circuit.

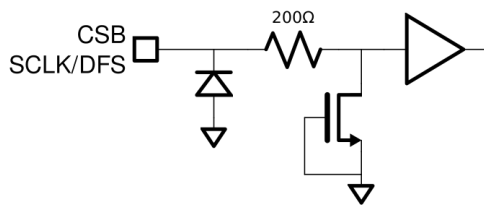


Figure 22: Equivalent CSB or SCLK/DFS Input Circuit.

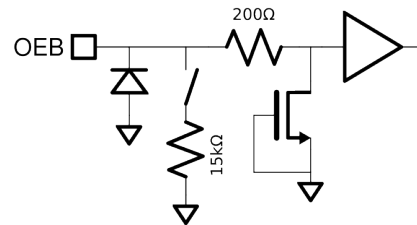


Figure 23: Equivalent OEB Input Circuit.

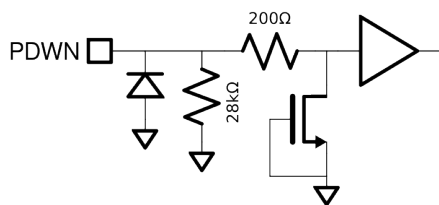


Figure 24: Equivalent PDWN Input Circuit.

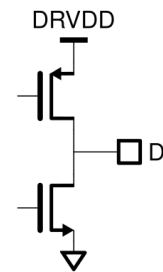


Figure 25: Equivalent Digital Output Circuit.



Figure 26: Equivalent LVDS output Circuit.

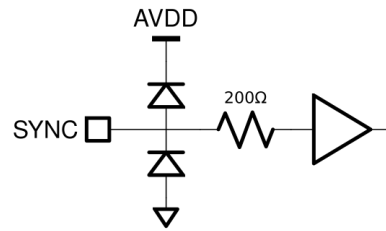


Figure 27: Equivalent SYNC Input Circuit.



Figure 28: Equivalent SENSE Input Circuit.

## THEORY OF OPERATION

### ADC Architecture

The ADC uses a pipelined architecture and innovative patented switched-capacitor circuits. Its fully differential design provides exceptional immunity to power supply noise and minimizes reference voltage self-modulation. A built-in Sample-and-Hold (S/H) function is integrated into the input stage of the pipeline structure.

### Analog Input

The input stage of the ADC behaves as a switched-capacitor network, presenting itself to the driving circuit as a combination of a switch and a sampling capacitor. The capacitor is reset prior to each conversion cycle, effectively eliminating non-linear memory effects commonly observed in some pipelined ADC architectures. The ADC does not include an internal common-mode bias therefore, the driving source must provide an appropriate common-mode voltage.

### Differential Clock Input

The SD9608 features a differential clock receiver with an integrated common-mode bias. For proper operation, the clock inputs should be AC-coupled using 10nF capacitors.

**Differential Clock Configuration.** For optimal jitter performance, a differential clock source is recommended. The differential clock signals to CLK+ and CLK- should be connected through a 10nF AC-coupling capacitors.

**Single-Ended Clock Configuration.** If a single-ended clock source is used, the signal source should be AC-coupled to the CLK+ pin. In this configuration, a 10nF capacitor should be connected between the CLK- pin and analog ground to maintain proper biasing.

**Clock Jitter Considerations.** Clock jitter has a significant impact on the ADC's signal-to-noise ratio (SNR). The sensitivity to jitter increases with input signal frequency. For best performance, a low-noise differential clock with fast edge transitions should be used.

**Note:** In some conditions the part can enter in manufacturing test mode if both differential clock inputs are held low for more than 1ms. This behavior can be prevented by writing 1 to register *0x4cf*, bit[15].

### Clock Divider

The ADC includes a programmable clock divider that allows the input clock to be divided by integer values from 2 to 8. The divider is configured by setting register *0x463*, bits [7:5], to the desired division value. A value of 0 (default) bypasses the divider entirely.

By default, the divider starts asynchronously. If the application requires synchronization across multiple ADC devices, the SYNC pin provides means for aligning clock dividers to guarantee sampling on the same clock edge. If clock divider is bypassed, this feature is not needed.

Synchronization is enabled by setting register *0x463*, bit [10], to 1. When the bit is 0, SYNC pin is ignored. SYNC is a level sensitive, active high, reset pin that is captured on the falling edge of the input clock. As long as SYNC is high, the divider stays in reset. It starts dividing on the first falling clock edge after SYNC goes low.

Make sure that the falling edge of SYNC meets the specified setup and hold times relative to the input clock, as shown in Table 13. Pay attention to the length matching of the clock and SYNC routing to the multiple ADC chips. For test and debugging purposes, the level of received and captured SYNC signal can be read from register *0x4ff*, bit [10].

**Clock Duty-Cycle Requirements.** The ADC utilizes both the rising and falling edges of the input clock (or the divided clock, if the divider is enabled) for internal sampling operations. To achieve optimal performance, especially at the maximum sampling rate, the clock duty cycle should be as close to 50% as possible.

When the divider is enabled with an even divisor, a 50% duty cycle is guaranteed by design. If the application uses a clock with a non-ideal duty cycle, a Duty Cycle Stabilizer (DCS) can be enabled to improve performance.

## ADC Self-Calibration

The ADC includes an automatic calibration mechanism that is executed at power-up to ensure optimal performance. It calibrates out capacitor mismatch and the effects of operational amplifier finite gain and bandwidth. For best results, calibration should be performed at the actual sampling rate used during operation. To support this, the device continuously monitors the sampling clock frequency and automatically re-triggers calibration if a significant change is detected. This feature can be disabled by setting register *0x4c9*, bit[0], to 1.

Manual calibration can also be initiated by toggling both *0xdc1*, bit[4] and *0xcc1*, bit[4] from 0 to 1. The calibration process is implemented using a state-machine architecture, ensuring a deterministic and predictable calibration time. By default the calibration takes 46 million ADC sampling clock cycles. Calibration completion status can be read from *0xdef*, bit[0] for the first ADC and *0xcef*, bit[0] for the second ADC after the status readback is enabled by writing *0x1c* to both *0xdeb* and *0xceb*. Bit value 1 indicates that calibration is complete.

In addition, the ADC supports a Background Calibration (BGC) mode, which is disabled by default. When enabled, parameters for compensating changes in operational amplifier gain and bandwidth are continuously updated. BGC is beneficial in environments with large temperature variations near the hot end of the specified operating temperature range. For its operation, BGC uses a dither signal which is injected into the ADC input signal path. This dither consumes approximately 0.8dB of the ADC's input range, resulting in earlier clipping compared to when BGC is disabled. When BGC is enabled calibration completion status bit remains 0.

To enable BGC:

- Write *0b01* to register *0xde1*, bits [15:14]
- Write *0b01* to register *0xce1*, bits [15:14]
- Write *0x0d80* to register *0xdcf*
- Write *0x0d80* to register *0xccf*
- Write *0b0* to register *0xde3*, bit [3]
- Write *0b0* to register *0xce3*, bit [3]

## Stand-by and Power-Down Modes

The SD9608 supports two power-saving modes that can be used when the ADC is not actively sampling. In both modes, the SPI interface (if enabled) remains operational.

**Power-Down Mode.** This mode disables most of the internal circuitry, resulting in the lowest residual supply current. It is ideal for applications requiring minimal power consumption during idle periods. Power-down mode can be enabled via:

- The PDWN pin when operating in the external pin mode, or
- Setting register *0x457*, bit[7], to 1.

**Standby Mode.** Standby mode offers a faster wake-up time compared to power-down mode, at the cost of slightly higher residual current. It is suitable for applications that require rapid recovery from idle states. To enable standby mode, set register *0x457*, bits [3] and [8], to 1.

**Note:** It is recommended to disable the ADC auto-calibration when using standby mode to avoid unintended calibration cycles during transitions.

## Pin Functions

The SD9608 offers several functions available via dual function pin controls (external pin mode vs. SPI mode). The SD9608 detects the SPI mode during the first SPI transaction after power-up. If the user does not want to program the device via the SPI interface, the dual function is available.

## DCS

The Duty-Cycle Stabilizer retimes the falling edge of the clock thus providing an internal clock signal with a 50% duty cycle. The DCS is useful in systems where the input clock has an uneven duty cycle. It can be enabled in the following ways:

- Via the DCS pin when operating in the external pin mode.
- Via register control by setting register *0x457*, bit[1], to 1.

## DFS

Data Format Select can be used to select between offset binary or two's complement when operating in the external pin mode.

## OEB

Output Enable (active-low). If the OEB pin is low, the output data drivers and output clock are enabled. If the OEB pin is high, the CMOS output data drivers and clock are placed in a high impedance state; while the LVDS drivers are switched off. The OEB function is not intended for rapid access to a shared data bus.

## RBIAS

External Reference Bias Resistor. The SD9608 requires a 30k $\Omega$ , 1% resistor, between pin RBIAS and AGND to set the default bias current for the ADC.

## VCM

Common-Mode Level Bias Output for Analog Input. The VCM pin provides a DC voltage that can be used to bias the ADC input common-mode level, either directly using a passive circuit or indirectly as a common-mode reference voltage for the driving active device. In most use cases, the default common-mode voltage level is optimal. The common-mode voltage level can be changed by register *0xf11*, bits [4:3].

## VREF

The ADC supports both internal (default) and external voltage reference sources, selectable via the VREF pin. The selection between internal and external reference voltage can be made in one of two ways:

- Using the SENSE pin: a logic high level selects the external reference.
- Via register control: setting register *0x45d*, bits [5] and [12] to 1 selects the external reference.

Internal Reference Output. When the internal voltage reference is used, the VREF pin can function as a reference output. This output can be enabled by setting register *0x45d*, bits [14:13], to 0x3.

If the SENSE pin is held low, the reference output is enabled by default. To disable the reference output in this configuration, set register *0x45d*, bits [14:13], to 0x1.

The internal vref can be adjusted with *0x45d* bits [4:1]. Usually the default value yields the optimal performance.

## SERIAL PORT INTERFACE

The SD9608 uses a 3-wire Serial Port Interface (SPI) that gives the user flexibility to configure the converter for specific functions, depending on the application, through a register space provided inside the ADC. The interface signals are:

- SCLK defines the bit rate at which serial data is driven onto, and sampled from, the bus;
- CSB defines the boundaries of a basic data 'unit', comprised of multiple serial bits;
- SDIO is the serial data IO wire;

The read and write cycles are described in the figure below. The complete instruction cycle is 32-bits long. The falling edge of CSB combines with the rising edge of SCLK marks the start of the instruction cycle. The address space is 13 bits long ( $A < 12:0 >$ ) and the data is 16 bits wide ( $D < 15:0 >$ ).

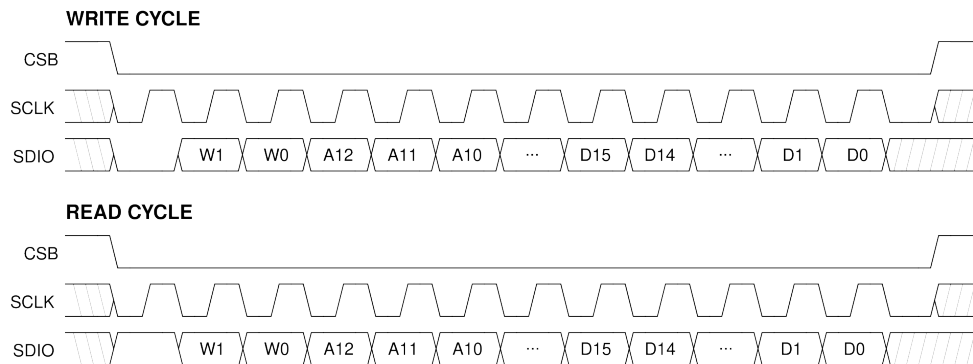


Figure 29: 3-wire SPI timing.

Table 19. SPI Timing.

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT
Setup time between the data and the rising edge of SCLK	$t_{DS}$	2			ns
Hold time between the data and the rising edge of SCLK	$t_{HD}$	2			ns
Period of the SCLK	$t_{SCLK}$	40			ns
Setup time between CSB and SCLK	$t_{S,CSB-SCLK}$	2			ns
Hold time between CSB and SCLK	$t_{H,CSB-SCLK}$	2			ns
Minimum period that SCLK should be in a logic high state	$t_{SCLK,high}$	10			ns
Minimum period that SCLK should be in a logic low state	$t_{SCLK,low}$	10			ns
Time from SCLK falling edge to SDIO switching from input to output	$t_{SDIO,EN}$	10			ns
Time from SCLK falling edge to SDIO switching from output to input	$t_{SDIO,DIS}$	10			ns

Two bits, W1 and W0, determine how many bytes of data that can be transferred in the same write cycle (see Table 20). If more than 16 bits (2 Bytes) of data are being transferred the address is increased sequentially.

Table 20. SPI Word Length.

[W1,W0]	Data length
00	Not supported
01	Two bytes of data can be transferred
10	Not supported
11	Four bytes of data can be transferred

The SPI pins should not be active when the full dynamic performance of the ADC is required. Noise from SCLK, CSB and the data transactions can degrade ADC performance.

## OUTPUT MODE

### Data Scrambler

Interference originating from the digital outputs of the ADC can be difficult to eliminate entirely. Such interference may result from capacitive or inductive coupling mechanisms, or from shared impedance paths in the ground plane. Even minimal coupling coefficients can introduce deterministic spurious tones into the ADC's output frequency spectrum. To mitigate this, digital output scrambling techniques can be employed prior to off-chip transmission. By randomizing the bit patterns, the spectral energy of these spurs is dispersed, effectively reducing their peak amplitudes and minimizing their impact on signal integrity.

The SD9608 can apply an exclusive-OR logic operation between the LSB and all other data output bits, while the LSB, overflow and clock outputs are not affected.



When this function is used, the receiver must apply the same function to unscramble the received data.

The data scrambler is enabled by programming control register *0x4b5*, bit[13].

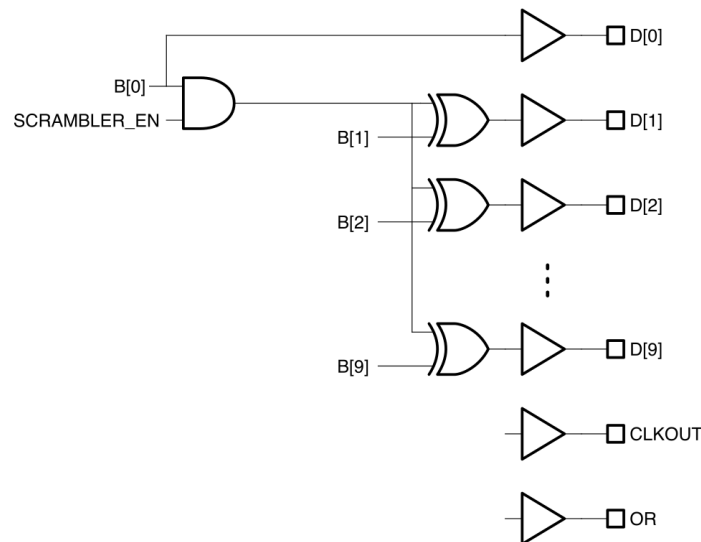


Figure 30: SD9608 Data Scrambler.

### Alternate Bit Polarity

The alternate bit polarity is particularly effective to suppress digital feedback and minimize noise coupling on the PCB when the ADC input signal is near mid-scale and of very small amplitude. In this case, the digital output tends to toggle between patterns dominated by either logic high or logic low states. This synchronized switching of multiple bits can induce significant transient currents in the ground plane, leading to increased digital noise. This mode, when activated, inverts all odd-numbered data output bits prior to the output buffer stage while even-numbered bits, along with the overflow and clock output, remain unaffected thus ensuring that approximately half of the output bits transition are high while the other half transition are low. This balanced switching behavior helps cancel out opposing current flows in the ground return path, thereby reducing overall ground noise. At the receiving end, the original data can be reconstructed by inverting the same odd-numbered bits. This mode operates independently of the digital output randomization feature, both functions can be enabled or disabled separately. The Alternate Bit Polarity mode is configured via serial programming of control register *0x4b5*, bit[14].

### Output Test Modes

The output test options are described in Table 21 and are selected via SPI programming at register *0x4b5*, bits [5:2].

When an output test mode is enabled, the analog section of the ADC is disconnected from the digital back-end blocks and the test pattern is run through the output formatting block. These tests require an active input clock.

There are two pseudo-random number generators available, PN23 and PN9. The PN23 generator ( $X^{23}+X^{18}+1$ ), selected by register *0x4b5*, bits [5:2], set to 0x5, can be reset by setting register *0x4b5*, bit [12], low; while the PN9 generator ( $X^9+X^6+1$ ), selected by register *0x4b5* set to 0x6, can be reset by setting register *0x4b5*, bit [11], low.

Table 21. Output Test Modes.

Mode	Function
0	Pass-Through
1	Midscale
2	+FS
3	-FS
4	Checkerboard
5	PN23
6	PN9
7	1/0 word toggle
8	User input
9	1/0 bit toggle
10	1x sync
11	1-bit high
12	Mixed frequency
13	Unused
14	Unused
15	Ramp

Pass-through and test patterns 1, 2, 3, 5 and 6 are subject to output formatting, while the other test modes are not. Test patterns 1, 8 and 15 can be applied to either one channel or both channels using *0x4b5*, bit[7:6]. Patterns 4 and 7 can be toggled between the pattern and its inverse while test pattern 8 can be selected using registers *0x4bb*, *0x4bd*, *0x4bb* and *0x4bb*.

## CONTROL REGISTERS

In this section the control registers are described. The template for each register is as follows:

Address: <HEX value>		RW or RO	Default: <HEX value>
bit field	default value	field description.	

where: **RW** indicates a Read/Write register and **RO** indicates a Read-Only register. If the register is read-only, the default value is omitted.

Registers not explicitly described in the following tables should not be written.



When changing control register values, read-modify-write procedure should be used. Some registers contain reserved bit fields for engineering purposes. This avoids inadvertently changing the values of those bits.

### 0x400 - CHIP\_TOP

Address: 0x455		RW	Default: 0x1
[0]	0x1	Soft reset (active low).	

Address: 0x457		RW	Default: 0x015
[0]	0x1	Duty Cycle Stabilizer enable.	
[1]	0x0	Duty Cycle Stabilizer on/off in SPI mode.	
[2]	0x1	External output enable (OE/OEB) control 0: Output Enabled 1: Output depends on pin OE/OEB	
[3]	0x0	Output disable 0: Output depends on OE/OEB control and OE/OEB pin 1: Disabled	
[6:4]	0x1	Reserved.	
[7]	0x0	Software power down.	
[8]	0x0	Software sleep mode.	

Address: 0x45d		RW	Default: 0x0095
[0]	0x1	ADC reference voltage enable.	
[4:1]	0xa	ADC reference voltage value.	
[5]	0x0	Set reference. 0: Internal 1: External from VREF pin	
[11:6]	0x2	Reserved.	
[12]	0x0	Enable Internal vs. External VREF selection using bit 5.	
[13]	0x0	Enable VREF out selection using bit 14.	
[14]	0x0	Enable VREF pin as reference voltage output.	

Address: 0x463		RW	Default: 0x019
[0]	0x1		Enable clock receiver.
[2:1]	0x0		Clock RX common-mode voltage bias.
[4:3]	0x3		Clock RX input stage bias current.
[7:5]	0x0		Clock RX divider control. 0: Bypass 1: Divide by 2 ... 7: Divide by 8
[8]	0x0		Enable on-chip 100Ohm termination.
[9]	0x0		Clock polarity control when DCS is enabled.
[10]	0x0		Enable SYNC pin synchronization.

Address: 0x465		RW	Default: 0x0
[2:0]	0x0		Output data interleaver. 0: pass through, no interleaving 1: pass through, channels swapped, no interleaving 2: N/A 3: N/A 4: parallel ADC_A/ADC_B interleaving 5: parallel ADC_B/ADC_A interleaving 6: even-odd interleaving 7: odd-even interleaving

Address: 0x467		RW	Default: 0x3850
[0]	0x0		LVDS enable.
[1]	0x0		LVDS reduced swing mode.
[10:2]	0x000		Reserved.
[13:11]	0x7		LVDS amplitude.
[15:14]	0x0		Reserved.

Address: 0x473		RW	Default: 0x0000
[4:0]	0x0		Reserved.
[9:5]	0x0		Output data delay in parallel CMOS mode.
[9]	0x0		Output data sending clock polarity in parallel CMOS mode.
[13:10]	0x0		Output clock delay.
[14]	0x0		Output clock polarity.

Address: 0x475		RW	Default: 0x1
[0]	0x1		Enable VCM.

Address: 0x4b5		RW	Default: 0x18c0
[1:0]	0x0		Output format. 0: Offset binary 1: Signed binary 2: Gray code 3: N/A
[5:2]	0x0		Output test mode select (see Table 21).
[6]	0x1		Output test channel CH. A 0: Disable 1: Enable
[7]	0x1		Output test channel CH. B 0: Disable 1: Enable
[8]	0x0		Output test toggle mode. Toggle between user test pattern 0 and 1.
[10:9]	0x0		Reserved.
[11]	0x1		PN9 generator reset (active low)
[12]	0x1		PN23 generator reset (active low)
[13]	0x0		Enable the output data scrambler.
[14]	0x0		Enable alternate bit polarity switch.
Address: 0x4b7		RW	Default: 0x0092
[15:0]	0x0092		PN9 initial seed.
Address: 0x4b9		RW	Default: 0x3aff
[15:0]	0x3aff		PN9 initial seed.
Address: 0x4bb		RW	Default: 0x0000
[15:0]	0x0000		User test pattern 0 (CH. A).
Address: 0x4bb		RW	Default: 0x0000
[15:0]	0x0000		User test pattern 1 (CH. A).
Address: 0x4bf		RW	Default: 0x0000
[15:0]	0x0000		User test pattern 0 (CH. B).
Address: 0x4c1		RW	Default: 0x0000
[15:0]	0x0000		User test pattern 1 (CH. B).
Address: 0x4c9		RW	Default: 0x0000
[0]	0x0		Disable auto-recalibration.
[15:1]	0x0000		Reserved.
Address: 0x4cf		RW	Default: 0x0035
[0]	0x1		Clock RX second stage bias current bit [0].
[1]	0x0		Reserved.
[2]	0x1		Clock RX second stage bias current bit [1].
[14:3]	0x006		Reserved.
[15]	0x0		Disable production test mode.

Address: 0x4d3		RW	Default: 0x07
[3:0]	0x7		LVDS common mode voltage.
[7:4]	0x0		Reserved.

Address: 0x4fd		RO	Default: N/A
[2:0]			Chip revision.
[6:3]			Label ID.
[8:7]			Reserved.
[10:9]			Resolution ID for device 0: 10-bit 1: 12-bit 2: 14-bit 3: 16-bit
[13:11]			Speed ID for device.

Address: 0x4ff		RO	Default: N/A
[0]			Reserved.
[1]			Analog Supply Ready.
[2]			Digital Supply Ready.
[3]			I/O Supply Ready.
[4]			Sense pin status.
[5]			SPI enabled.
[6]			Power down pin status.
[9:7]			Reserved.
[10]			SYNC pin status.

## 0xF00 - ADC\_DUAL

Address: 0xf03		RW	Default: 0x7f8
[0]	0x0		Enable top level bias.
[2:1]	0x0		Reserved.
[3]	0x1		ADC_B enable.
[10:5]	0x3f		Mask for enable pin.

Address: 0xf05		RW	Default: 0x30
[5:0]	0x30		Mask for sleep pin.
[6]	0x0		Sleep ADC_B.
[7]	0x0		Sleep ADC_A.

Address: 0xf07		RW	Default: 0x40
[0]	0x0		Digital clock enable.
[1]	0x0		Analog clock enable.
[2]	0x0		Reserved.
[3]	0x0		Clock select.
[5:4]	0x0		Reserved. 0: ADC_B 1: ADC_A
[6]	0x1		ADC clock generator reset.
[7]	0x0		Reserved.

Address: 0xf09		RW	Default: 0x40
[2:0]	0x0		Channel B source 001: ADC B (default) 011: ADC A 111: (ADC A + ADC B)/2
[5:3]	0x0		Channel A source 001: ADC A (default) 011: ADC B 111: 0
[6]	0x1		Reserved.

Address: 0xf0b		RW	Default: 0x24
[2:0]	0x4		Reserved.
[5:3]	0x4		ADC master bias.

Address: 0xf11		RW	Default: 0x0b
[2:0]	0x3		Main bias.
[4:3]	0x1		VCM voltage control.

## 0xDC0 - ADC\_A

Address: 0xdc1		RW	Default: 0xbfff
[0]	0x1		Enable.
[1]	0x1		Clock enable.
[2]	0x1		Soft reset.
[3]	0x1		Reserved.
[4]	0x1		Calibration soft reset.
[6:5]	0x3		Reserved.
[10:7]	0xf		Enable mask for en_adc pin.
[15:11]	0x17		Sleep mask for sleep pin.

Address: 0xdc3		RW	Default: 0x0000
[3:0]	0x0		Clock phase.
[11:4]	0x00		Sampling clock fine delay.
[12]	0x0		Enable fine delay register control.
[14:13]	0x0		Reserved.

Address: 0xdc9		RW	Default: 0x6a5
[0]	0x1		Stg1 gain error calibration enable.
[1]	0x0		Stg1 gain error calibration only.
[8:2]	0x29		Reserved.
[9]	0x1		Stg1 enable background mode.
[11:10]	0x1		Reserved.

Address: 0xdcd		RW	Default: 0x1483
[2:0]	0x3		Stg1 calibration convergence speed in foreground mode.
[11:3]	0x090		Reserved.
[13:12]	0x1		Stg1 calibration randomization sequence in foreground mode.

Address: 0xdcf		RW	Default: 0xd85
[2:0]	0x5		Stg1 calibration convergence speed in background mode.
[11:3]	0x1b0		Reserved.

Address: 0xdd1		RW	Default: 0x2a5
[0]	0x1		Stage 2 gain error calibration enable.
[1]	0x0		Stage 2 gain error calibration only.
[8:2]	0x29		Reserved.
[9]	0x1		Stg2 enable background mode.
[11:10]	0x0		Reserved.

Address: 0xdd5		RW	Default: 0x1483
[2:0]	0x3		Stg2 calibration convergence speed in foreground mode.
[11:3]	0x090		Reserved.
[13:12]	0x1		Stg2 calibration randomization sequence in foreground mode.

Address: 0xdd7		RW	Default: 0x001
[2:0]	0x1		Stg2 calibration convergence speed in background mode.
[11:3]	0x0		Reserved.

Address: 0xdd9		RW	Default: 0x0a5
[0]	0x1		Stg3 gain error calibration enable.
[1]	0x0		Stg3 gain error calibration only.
[7:2]	0x29		Reserved.
[8]	0x0		Stg3 enable background mode.
[10:9]	0x0		Reserved.

Address: 0xddd		RW	Default: 0x16c3
[2:0]	0x3		Stg3 calibration convergence speed in foreground mode.
[11:3]	0x0d8		Reserved.
[13:12]	0x1		Stg3 calibration randomization sequence in foreground mode.

Address: 0xddf		RW	Default: 0x000
[2:0]	0x0		Stg3 calibration convergence speed in background mode.
[11:3]	0x0		Reserved.

Address: 0xde1		RW	Default: 0xbb28
[7:0]	0x28		Time allocated for calibration.
[8]	0x1		Enable calibration.
[9]	0x1		Enable foreground calibration.
[10]	0x0		Reserved.
[11]	0x1		Enable stg1 calibration.
[12]	0x1		Enable stg2 calibration.
[13]	0x1		Enable stg3 calibration.
[14]	0x1		Background calibration parallel mode.
[15]	0x1		Disable background calibration mode for all stages.

Address: 0xde3		RW	Default: 0x8
[2:0]	0x0	Reserved.	
[3]	0x1	Clipping control to reserve some headroom for background calibration signals. Active low.	

Address: 0xde7		RW	Default: 0x04
[2:0]	0x4	Reserved.	
[4:3]	0x0	Output data timing.	

Address: 0xdeb		RW	Default: 0x00
[7:0]	0x00	Testbus MUX control.	

Address: 0xdef		RO	Default: N/A
[15:0]		Testbus read-back register.	

### 0xCC1 - ADC\_B

Address: 0xcc1		RW	Default: 0xbfff
[0]	0x1	Enable.	
[1]	0x1	Clock enable.	
[2]	0x1	Soft reset.	
[3]	0x1	Reserved.	
[4]	0x1	Calibration soft reset.	
[6:5]	0x3	Reserved.	
[10:7]	0xf	Enable mask for en_adc pin.	
[15:11]	0x17	Sleep mask for sleep pin.	

Address: 0xcc3		RW	Default: 0x0000
[3:0]	0x0	Clock phase.	
[11:4]	0x00	Sampling clock fine delay.	
[12]	0x0	Enable fine delay register control.	
[14:13]	0x0	Reserved.	

Address: 0xcc9		RW	Default: 0x6a5
[0]	0x1	Stg1 gain error calibration enable.	
[1]	0x0	Stg1 gain error calibration only.	
[8:2]	0x29	Reserved.	
[9]	0x1	Stg1 enable background mode.	
[11:10]	0x1	Reserved.	

Address: 0xccd		RW	Default: 0x1483
[2:0]	0x3	Stg1 calibration convergence speed in foreground mode.	
[11:3]	0x090	Reserved.	
[13:12]	0x1	Stg1 calibration randomization sequence in foreground mode.	

Address: 0xccf		RW	Default: 0xd85
[2:0]	0x5	Stg1 calibration convergence speed in background mode.	
[11:3]	0x1b0	Reserved.	

Address: 0xcd1		RW	Default: 0x2a5
[0]	0x1		Stage 2 gain error calibration enable.
[1]	0x0		Stage 2 gain error calibration only.
[8:2]	0x29		Reserved.
[9]	0x1		Stg2 enable background mode.
[11:10]	0x0		Reserved.

Address: 0xcd5		RW	Default: 0x1483
[2:0]	0x3		Stg2 calibration convergence speed in foreground mode.
[11:3]	0x090		Reserved.
[13:12]	0x1		Stg2 calibration randomization sequence in foreground mode.

Address: 0xcd7		RW	Default: 0x001
[2:0]	0x1		Stg2 calibration convergence speed in background mode.
[11:3]	0x0		Reserved.

Address: 0xcd9		RW	Default: 0x0a5
[0]	0x1		Stg3 gain error calibration enable.
[1]	0x0		Stg3 gain error calibration only.
[7:2]	0x29		Reserved.
[8]	0x0		Stg3 enable background mode.
[10:9]	0x0		Reserved.

Address: 0xcdD		RW	Default: 0x16c3
[2:0]	0x3		Stg3 calibration convergence speed in foreground mode.
[11:3]	0x0d8		Reserved.
[13:12]	0x1		Stg3 calibration randomization sequence in foreground mode.

Address: 0xcdf		RW	Default: 0x000
[2:0]	0x0		Stg3 calibration convergence speed in background mode.
[11:3]	0x0		Reserved.

Address: 0xce1		RW	Default: 0xbb28
[7:0]	0x28		Time allocated for calibration.
[8]	0x1		Enable calibration.
[9]	0x1		Enable foreground calibration.
[10]	0x0		Reserved.
[11]	0x1		Enable stg1 calibration.
[12]	0x1		Enable stg2 calibration.
[13]	0x1		Enable stg3 calibration.
[14]	0x1		Background calibration parallel mode.
[15]	0x1		Disable background calibration mode for all stages.

Address: 0xce3		RW	Default: 0x8
[2:0]	0x0		Reserved.
[3]	0x1		Clipping control to reserve some headroom for background calibration signals. Active low.

Address: 0xce7		RW	Default: 0x04
[2:0]	0x4	Reserved.	
[4:3]	0x0	Output data timing.	
Address: 0xceb		RW	Default: 0x00
[7:0]	0x00	Testbus MUX control.	
Address: 0xcef		RO	Default: N/A
[15:0].		Testbus read-back register.	

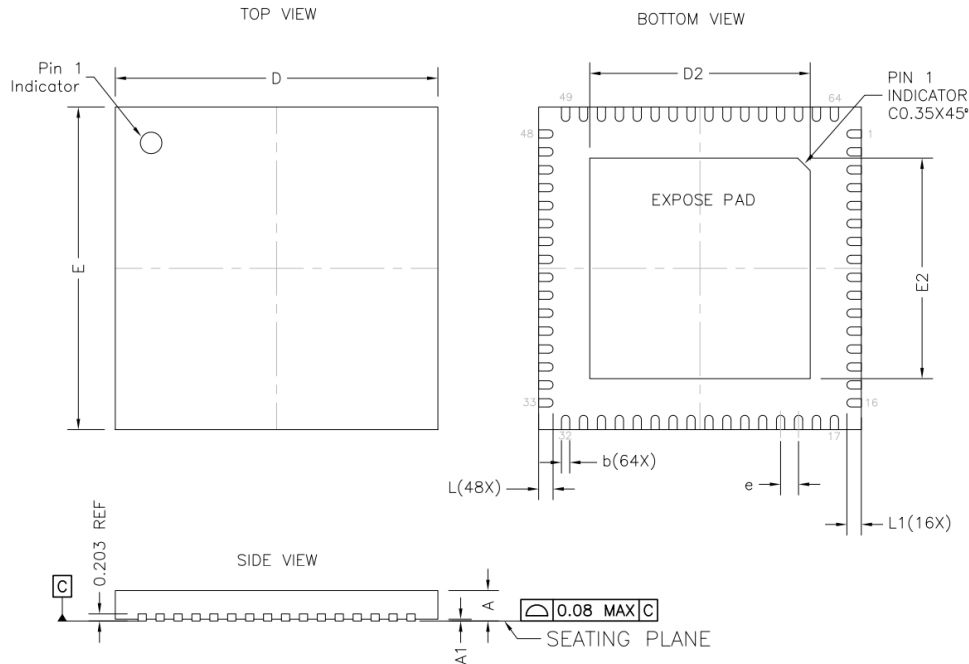
## ORDERING INFORMATION

Base Part No.	Orderable Part No. Full Tray	Orderable Part No. Tray with 50Pcs	Orderable Part No. Reel with 750pcs
SD9608-105	SD9608-105-A-QC9-TB	SD9608-105-A-QC9-TA	SD9608-105-A-QC9-RD

EVK	Part No.
CMOS	SDE1115-C
LVDS	SDE1115-L

This product is protected by several U.S. Patents ([www.silannasemi.com/patents](http://www.silannasemi.com/patents)).

## PACKAGE DRAWING



DIMENSION TABLE			
SYMBOL	MINIMUM	NOMINAL	MAXIMUM
A	0.70	0.75	0.80
A1	0.00	0.02	0.05
b	0.20	0.25	0.30
D	8.90	9.00	9.10
D2	6.10	6.15	6.20
E	8.90	9.00	9.10
E2	6.10	6.15	6.20
e	0.50 BSC		
L	0.35	0.40	0.45
L1	0.33	0.38	0.43

NOTE:

1. Dimensioning and tolerancing conform to ASME Y14.5-2009
2. All dimensions are in millimeters
3. N is the total number of terminals
4. Unilateral coplanarity zone applies to the exposed pas as well as the terminals
5. Lead Finish: 100% Sn

Figure 31: Package Dimensions.

## REVISION HISTORY

Version	Date	Comment
1.0	June 19, 2025	Initial Release.
2.0	July 30, 2025	Filled missing specifications. Changed RBIAS resistor to 30kΩ. Improved timing diagrams. Fixed typos.
3.0	November 5, 2025	Updated performance limits. Grouped similar pins together in pinout table. Added IO conversion table. Fixed typos.
4.0	December 9, 2025	Fixed typo in Calibration Settings table.

Silanna Semiconductor Proprietary and Confidential

Information furnished by Silanna Semiconductor is believed to be accurate and reliable. However, no responsibility is assumed for its use. Silanna Semiconductor makes no representation that the interconnection of its circuits as described herein will not infringe on existing patents rights. Specifications subject to change without notice.